

General Features

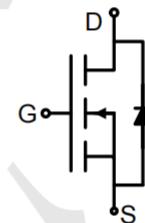
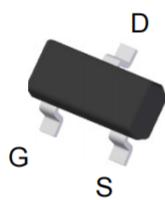
$V_{(BR)DSS}$	$R_{DS(on)}\text{MAX}$	I_D
60V	105mΩ@10V	3A
	125mΩ@4.5V	

Application

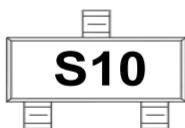
Load/Power Switching
Interfacing Switching
Battery Management for Ultra Small Portable
Logic Level Shift

Package and Pin Configuration

SOT23



Marking:



Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	3	A
Pulsed Drain Current (note 1)	I_{DM}	10	A
Power Dissipation	P_D	0.35	W
Thermal Resistance from Junction to Ambient (note 2)	$R_{\theta JA}$	357	°C/W
Junction Temperature	T_J	150	°C
Storage Temperature	T_{STG}	-55~+150	°C

Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
STATIC CHARACTERISTICS						
Drain-source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}} = 0\text{V}, I_D = 250\mu\text{A}$	60			V
Zero gate voltage drain current	I_{DSS}	$V_{\text{DS}} = 60\text{V}, V_{\text{GS}} = 0\text{V}$			1	μA
Gate-body leakage current	I_{GSS}	$V_{\text{GS}} = \pm 20\text{V}, V_{\text{DS}} = 0\text{V}$			± 100	nA
Gate threshold voltage (note 3)	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = V_{\text{GS}}, I_D = 250\mu\text{A}$	0.5		2	V
Drain-source on-resistance (note 3)	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}} = 10\text{V}, I_D = 3\text{A}$			105	$\text{m}\Omega$
		$V_{\text{GS}} = 4.5\text{V}, I_D = 3\text{A}$			125	$\text{m}\Omega$
Forward transconductance (note 3)	g_{FS}	$V_{\text{DS}} = 15\text{V}, I_D = 2\text{A}$	1.4			S
Diode forward voltage (note 3)	V_{SD}	$I_S = 3\text{A}, V_{\text{GS}} = 0\text{V}$			1.2	V
DYNAMIC CHARACTERISTICS (note 4)						
Input Capacitance	C_{iss}	$V_{\text{DS}} = 30\text{V}, V_{\text{GS}} = 0\text{V}, f = 1\text{MHz}$		247		pF
Output Capacitance	C_{oss}			34		pF
Reverse Transfer Capacitance	C_{rss}			19.5		pF
SWITCHING CHARACTERISTICS (note 4)						
Turn-on delay time	$t_{\text{d}(\text{on})}$	$V_{\text{GS}} = 10\text{V}, V_{\text{DD}} = 30\text{V}, I_D = 1.5\text{A}, R_{\text{GEN}} = 1\Omega$		6		ns
Turn-on rise time	t_r			15		ns
Turn-off delay time	$t_{\text{d}(\text{off})}$			15		ns
Turn-off fall time	t_f			10		ns
Total Gate Charge	Q_g	$V_{\text{DS}} = 30\text{V}, V_{\text{GS}} = 4.5\text{V}, I_D = 3\text{A}$		6		nC
Gate-Source Charge	Q_{gs}			1		nC
Gate-Drain Charge	Q_{gd}			1.3		nC



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TPUT3N06G-AE3-R

60V N-Channel MOSFET

Typical Electrical and Thermal Characteristics (Curves)

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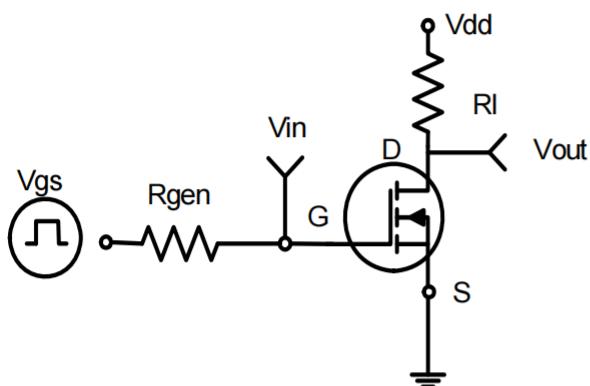


Figure 1:Switching Test Circuit

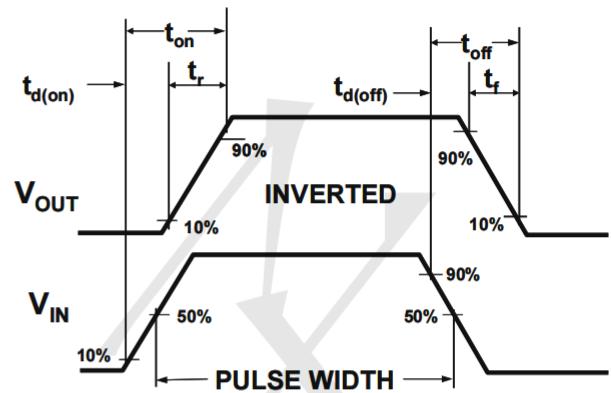
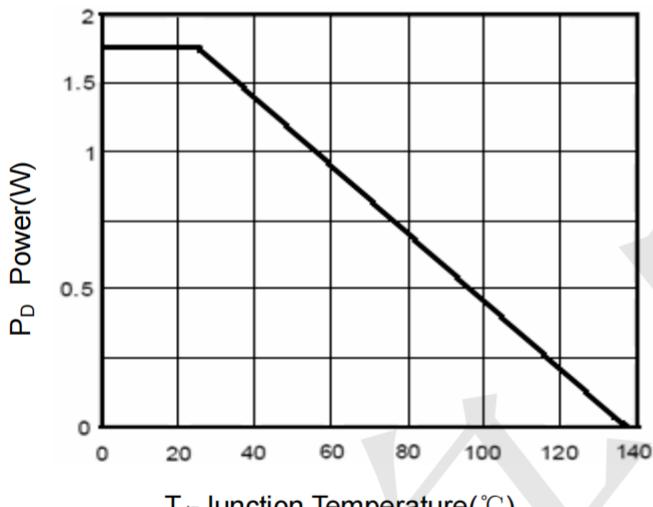
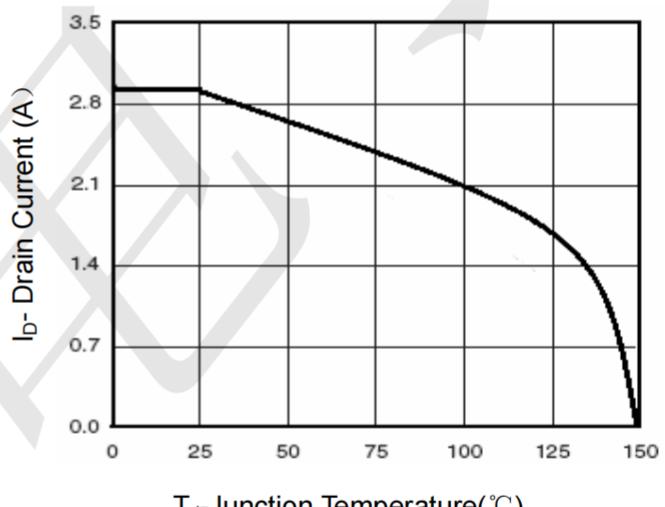


Figure 2:Switching Waveforms



T_j-Junction Temperature(°C)

Figure 3 Power Dissipation



T_j-Junction Temperature(°C)

Figure 4 Drain Current

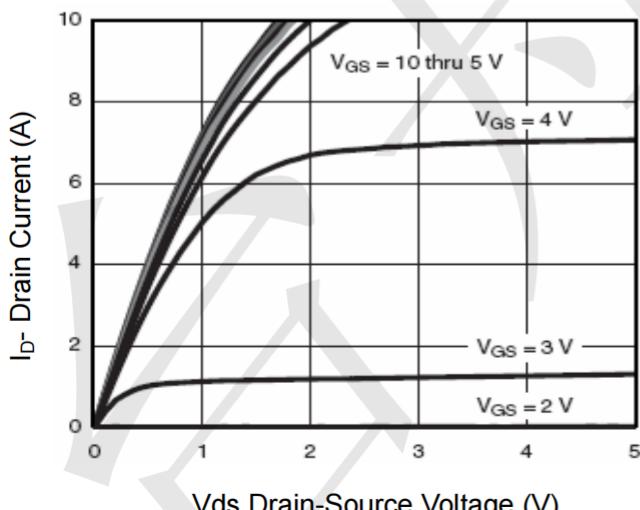


Figure 5 Output Characteristics

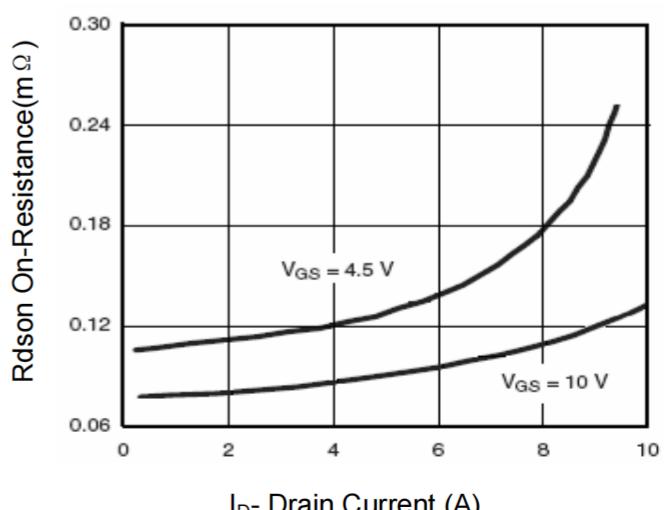


Figure 6 Drain-Source On-Resistance

Typical Electrical and Thermal Characteristics (Curves)

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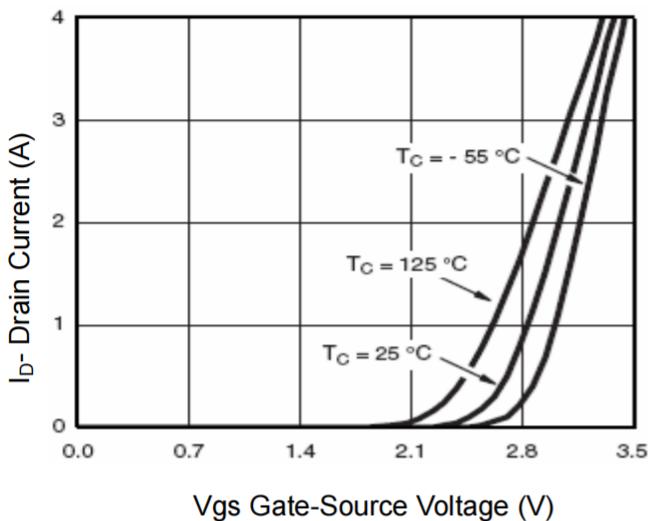


Figure 7 Transfer Characteristics

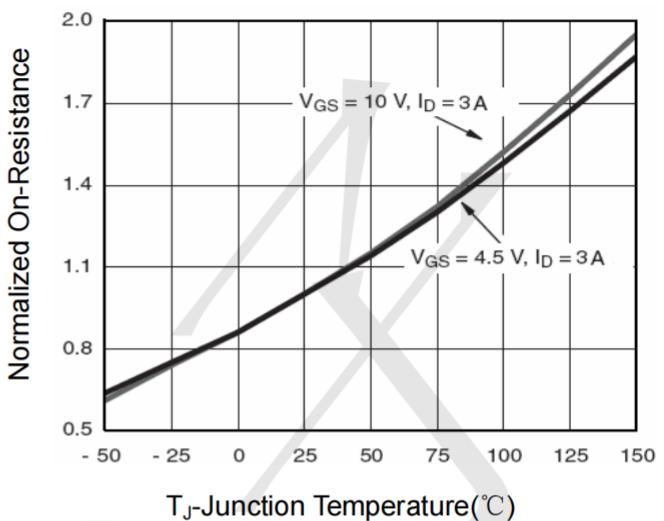


Figure 8 Drain-Source On-Resistance

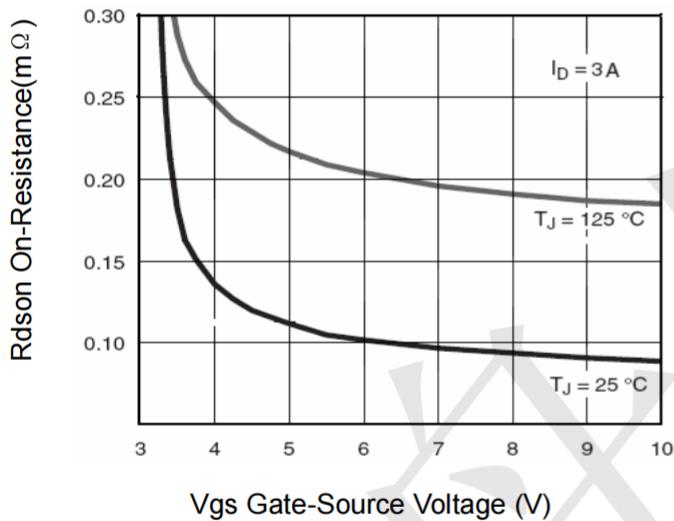


Figure 9 $R_{DS(on)}$ vs V_{GS}

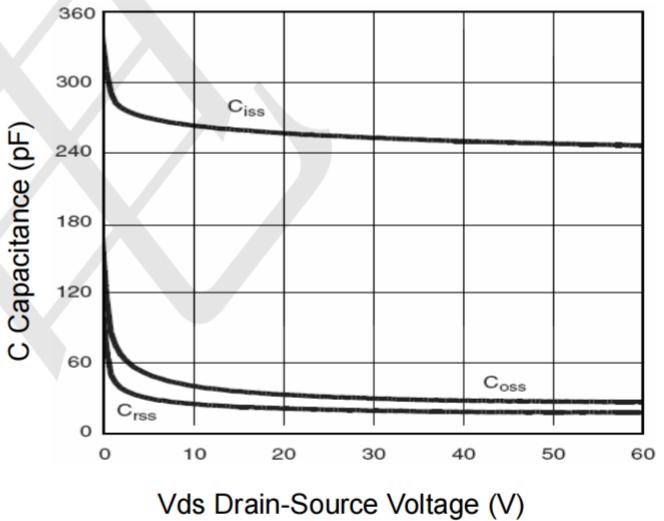


Figure 10 Capacitance vs V_{DS}

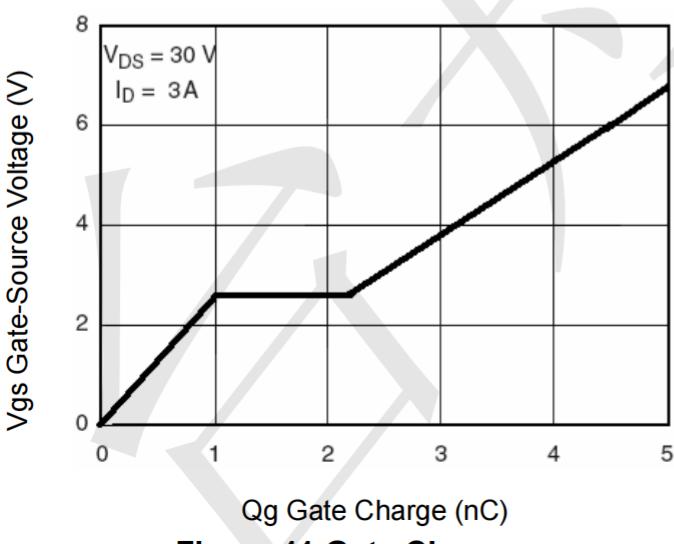


Figure 11 Gate Charge

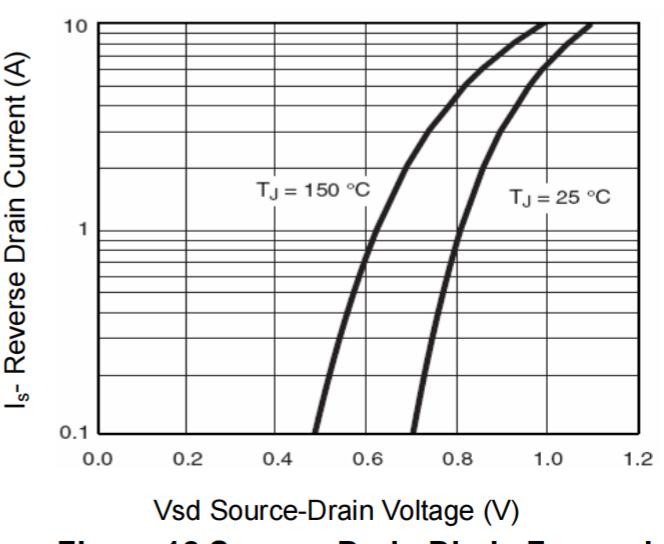


Figure 12 Source-Drain Diode Forward

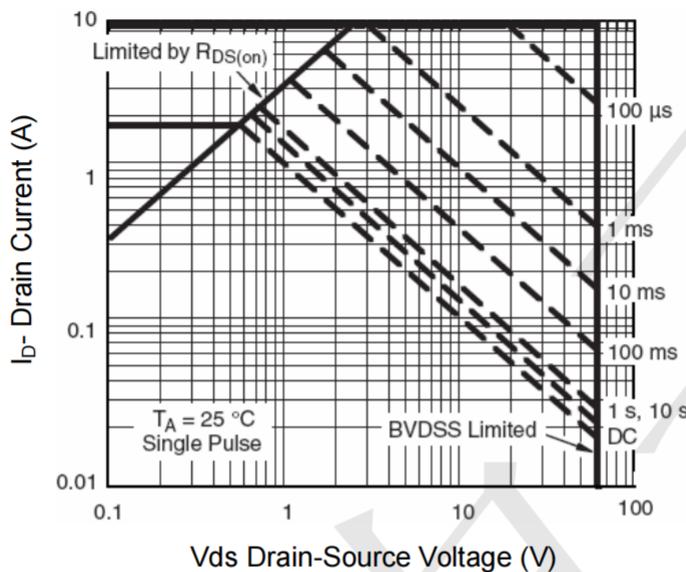


Figure 13 Safe Operation Area

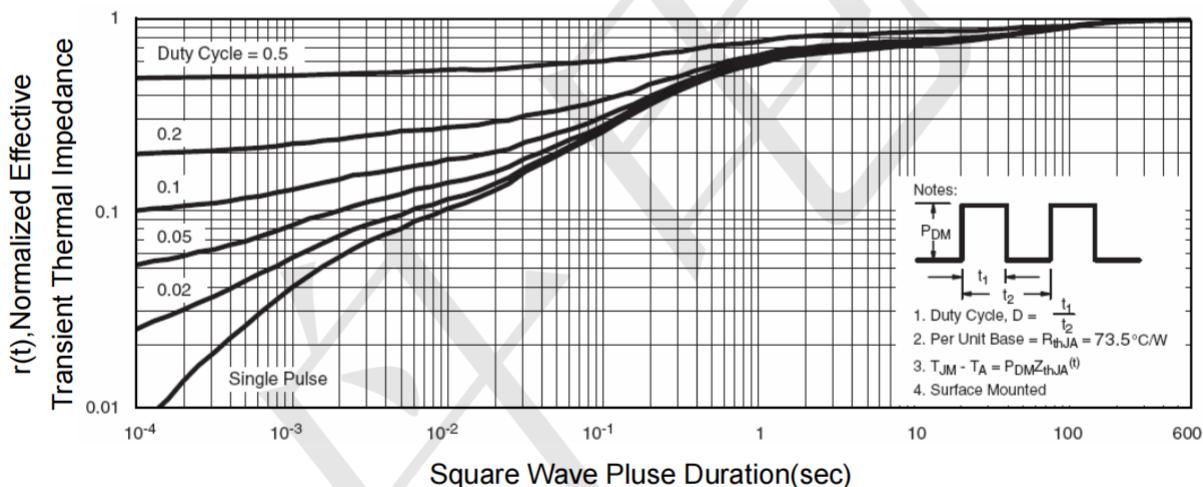
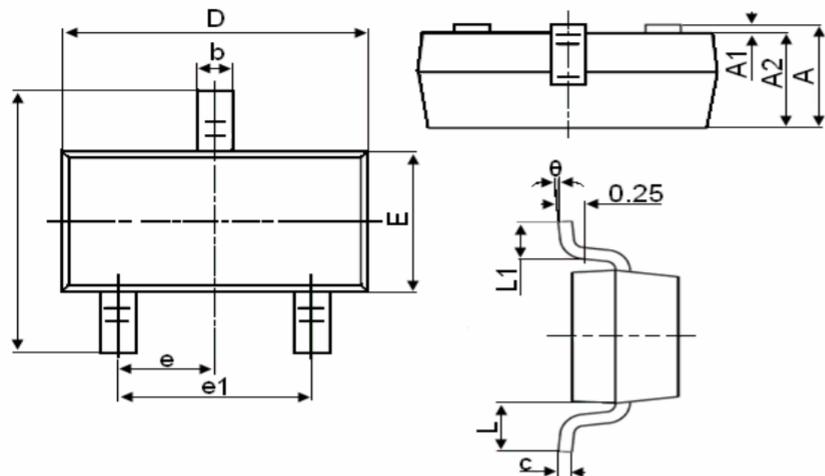


Figure 14 Normalized Maximum Transient Thermal Impedance

Package Outline Dimensions (SOT-23)

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Symbol	Dimensions in Millimeters	
	MIN.	MAX.
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950TYP	
e1	1.800	2.000
L	0.550REF	
L1	0.300	0.500
θ	0°	8°

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